

# STPS50U100C

# ULVF<sup>™</sup> power Schottky rectifier

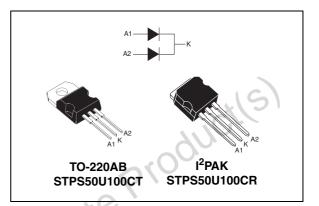
# Features

- ultralow forward voltage drop
- high current capability
- high frequency operation

## Description

The STPS50U100C is a dual power Schottky diode rectifier, suited for high frequency switch mode power supplies.

Featuring an ultralow forward voltage (ULVF) drop, this device, packaged in TO-220AB and I<sup>2</sup>PAK, is intended to be used in notebook, game station and desktop adaptors as well as server SMPS. It has been especially designed to help power supply manufacturers meet the recently introduced worldwide efficiency standards.



## Table 1. Device summary

Symbol	Value
I <sub>F(AV)</sub>	2 x 25 A
V <sub>RRM</sub>	100 V
V <sub>F</sub> (typ) (25 A @ 125 °C)	0.64 V
T <sub>j</sub> (max)	150 °C

TM: ULVF is a trademark of STMicroelectronics

### **Characteristics** 1

### Table 2. Absolute ratings (limiting values per diode at 25 °C, unless otherwise specified)

Symbol	Parameter			Value	Unit
V <sub>RRM</sub>	Repetitive peak reverse voltage			100	V
I <sub>F(RMS)</sub>	Forward rms current			50	А
I <sub>F(AV)</sub>	Average forward current, $\delta = 0.5$	T <sub>C</sub> = 120 °C T <sub>C</sub> = 105 °C	Per diode Per device	25 50	A
I <sub>FSM</sub>	Surge non repetitive forward current	t <sub>p</sub> = 10 ms, h	alf sine-wave	250	Α
T <sub>stg</sub>	Storage temperature range			-65 to + 150	°C
Тj	Maximum operating junction temperature <sup>(1)</sup>			150	°C
. dPtot	1				

### **Thermal resistance** Table 3.

1. dPtot dTj <	$\frac{1}{Rth(j-a)}$ condition to avoid thermal ru	naway for a diode on its own heatsink	900	
Table 3.	Thermal resistance	010		
Symbol		Parameter	Value	Unit
R <sub>th (j-c)</sub>	Junction to case	Per diode Per device	1.3 0.9	°C/W
R <sub>th (c)</sub>	Coupling	~105	0.45	°C/W

When the diodes 1 and 2 are used simultaneously:

 $\Delta T_{j}(\text{diode 1}) = P(\text{diode1}) \times R_{th(j-c)}(\text{Per diode}) + P(\text{diode2}) \times R_{th(c)}$ 

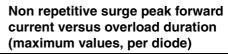
### Table 4. Static electrical characteristics

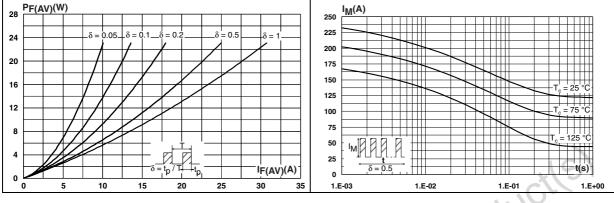
Symbol	Parameter	Tests co	onditions	Min.	Тур.	Max.	Unit
	010	T <sub>j</sub> = 25 °C	V <sub>R</sub> = 70 V	-	15	-	μA
I <sub>R</sub>	Reverse leakage current	T <sub>j</sub> = 125 °C	v <sub>R</sub> = 70 v	-	10	-	mA
'R	neverse leakage current	T <sub>j</sub> = 25 °C	V - V	-	30	200	μA
		T <sub>j</sub> = 125 °C	V <sub>R</sub> = V <sub>RRM</sub>	-	15	40	mA
105		T <sub>j</sub> = 25 °C	I <sub>F</sub> = 5 A	-	0.48	-	
		T <sub>j</sub> = 125 °C	1F – 2 A	-	0.38	-	
V <sub>F</sub>	Forward voltage drop	T <sub>j</sub> = 25 °C	l <sub>F</sub> = 15 A	-	0.58	-	V
۷F	Torward voltage drop	T <sub>j</sub> = 125 °C	1F - 13 A	-	0.54	-	v
		T <sub>j</sub> = 25 °C	I <sub>F</sub> = 25 A	-	0.67	0.73	
		T <sub>j</sub> = 125 °C	1 <sub>F</sub> – 23 A	-	0.64	0.7	

To evaluate the conduction losses use the following equation:  $P = 0.475 \times I_{F(AV)} + 0.009 I_{F}^{2}(RMS)$ 



# Figure 1. Average forward power dissipation Figure 2. versus average forward current (per diode)





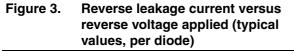


Figure 4. Average forward current versus ambient temperature  $(\delta = 0.5, \text{ per diode})$ 

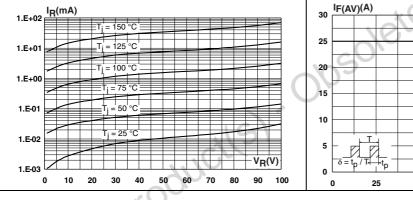


Figure 5. Relative variation of thermal impedance junction to case versus pulse duration

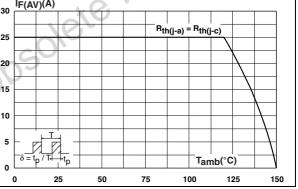
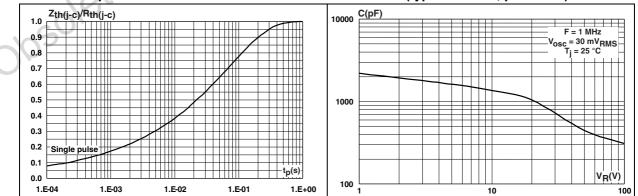


Figure 6. Junction capacitance versus reverse voltage applied (typical values, per diode)



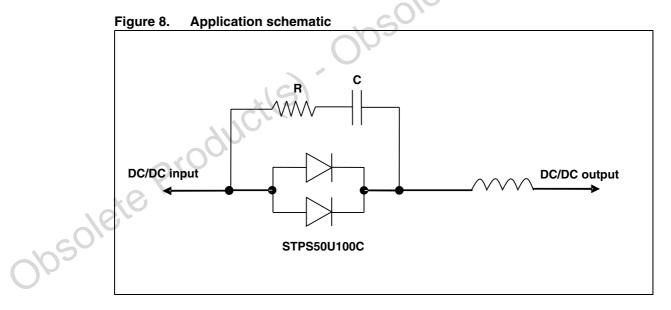


riguie 7. Torward	
50	I <sub>FM</sub> (A)
45	
40	
35	
30	T <sub>1</sub> = 125 °C (Maximum value)
25	
20	
15	(Typical value) T <sub>i</sub> = 25 °C (Maximum value)
10	
5	
0	0.0 0.1 0.2 0.3 0.4 0.5 0.6 0.7 0.8 0.9 1.0
Application ir	ct(S)

Figure 7. Forward voltage drop versus forward current (per diode)

## **Application information** 2

It is mandatory to ensure a peak reverse voltage below the  $V_{\rm RBM}$  absolute rating. ST recommends the use of an RC clamping snubber circuit in parallel with the STPS50U100C device.





# 3 Package information

- Epoxy meets UL94,V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.4 to 0.6 N·m

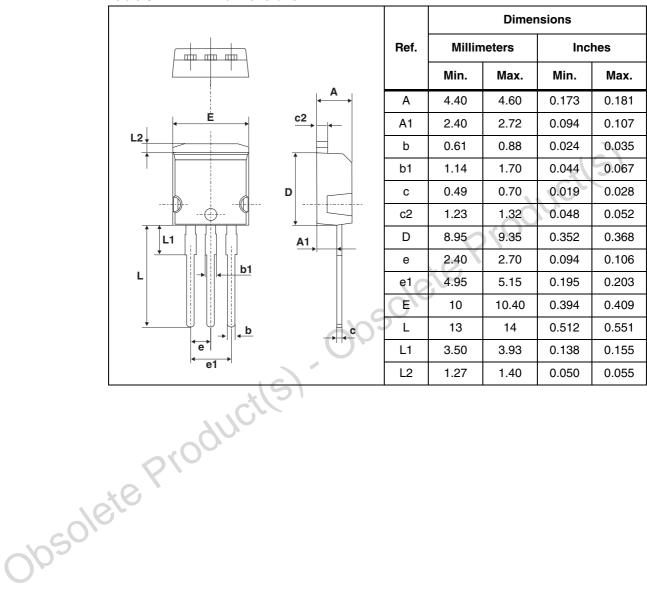
In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <u>www.st.com</u>. ECOPACK<sup>®</sup> is an ST trademark.

Table 5. TO-220AB dimensions

Γ				Dimer	sions	51
		Ref.	Millim	neters	Inc	hes
			Min.	Max.	Min.	Max.
		А	4.40	4.60	0.173	0.181
		С	1.23	1.32	0.048	0.051
	H2 A Dia C	D	2.40	2.72	0.094	0.107
		E	0.49	0.70	0.019	0.027
		F	0.61	0.88	0.024	0.034
		F1	1.14	1.70	0.044	0.066
		F2	1.14	1.70	0.044	0.066
	F2	G	4.95	5.15	0.194	0.202
		G1	2.40	2.70	0.094	0.106
		H2	10	10.40	0.393	0.409
	F, ←	L2	16.4	typ.	0.64	5 typ.
		L4	13	14	0.511	0.551
16	$\begin{array}{c c} & & & & \\ & & & \\ & &$	L5	2.65	2.95	0.104	0.116
5	G	L6	15.25	15.75	0.600	0.620
		L7	6.20	6.60	0.244	0.259
		L9	3.50	3.93	0.137	0.154
		М	2.6	typ.	0.10	2 typ.
		Dia.	3.75	3.85	0.147	0.151



Mounting (soldering) the I<sup>2</sup>PAK metal slug (heatsink) with alloy, like a surface mount device, IS NOT PERMITTED. A standard through-hole mounting is mandatory.



## Table 6.I<sup>2</sup>PAK dimensions



### **Ordering information** 4

### Table 7. **Ordering information**

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS50U100CT	STPS50U100C	TO-220AB	2.23 g	50	Tube
STPS50U100CR	STPS50U100C	I <sup>2</sup> PAK	1.49 g	50	Tube

For the latest information on available order codes see the product pages on www.st.com.

### **Revision history** 5

#### Table 8. **Document revision history**

		rision history
Date	Revision	Changes
17-Nov-2009	1	First release.
04-Nov-2010	2	Added trademark statement for UVLF.
	duct	



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